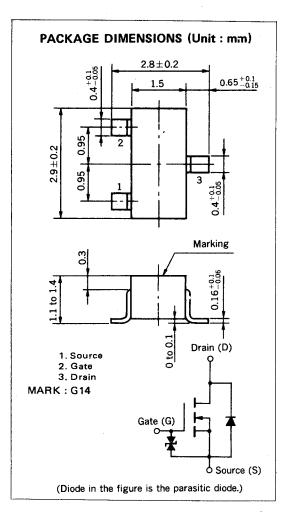


MOS FIELD EFFECT TRANSISTOR **2SK1581**

N-CHANNEL MOS FET FOR SWITCHING



The 2SK1581, N-channel vertical type MOS FET, can be driven by 2.5 V power supply.

As the MOS FET is driven by low voltage and does not require consideration of driving current, it is suitable for appliances including VCR cameras and headphone stereos which need power saving.

FEATURES

- Directly driven by ICs having a 3 V power supply.
- Not necessary to consider driving current because of its high input impedance.
- Possible to reduce the number of parts by omitting the bias resistor.

ABSOLUTE MAXIMUM RATINGS (TA = 25 °C)

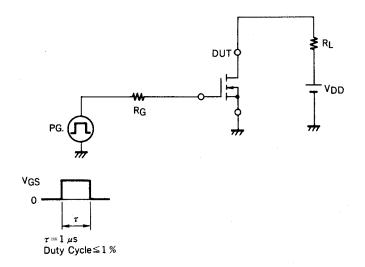
PARAMETER	SYMBOL	RATINGS	UNIT	TEST CONDITIONS VGS = 0		
Drain to Source Voltage	V _{DSS}	16	V			
Gate to Source Voltage	V _{GSS}	±16 V V _{DS} = 0 ±200 mA		V _{DS} = 0		
Drain Current	ID(DC)					
Drain Current	¹ D(pulse)	±400	mA	PW ≤ 10 ms, Duty Cycle ≤ 50 %		
Total Power Dissipation	PT	200	mW			
Channel Temperature	T _{ch}	150	°C			
Operating Temperature	T _{opt}	-55 to +80	°C			
Storage Temperature	T _{stg}	-55 to +150	°C			

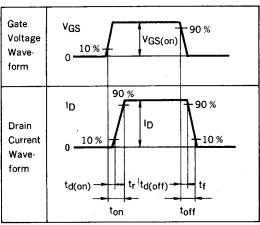


ELECTRICAL CHARACTERISTICS (TA = 25 °C)

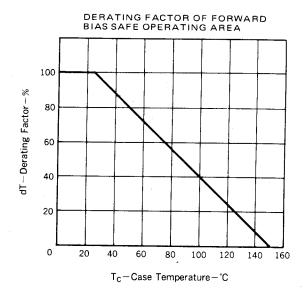
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS	
Drain Cut-off Current	IDSS			1.0	μА	V _{DS} = 16 V, V _{GS} = 0	
Gate Leakage Current	IGSS			±5.0	μА	V _{GS} = ±3 V, V _{DS} = 0	
Gate Cut-off Voltage	VGS(off)	0.8	1.1	1.6	V	$V_{DS} = 3.0 \text{ V, } I_{D} = 10 \mu\text{A}$	
Forward Transfer Admittance	lyfsl	20	70		mS	V _{DS} = 3.0 V, I _D = 10 mA	
Drain to Source On-State Resistance	RDS(on)1		3.2	5.0	Ω	V _{GS} = 2.5 V, I _D = 1 mA	
Drain to Source On-State Resistance	R _{DS(on)2}		2.2	3.0	Ω	V _{GS} = 4.0 V, I _D = 1 mA	
Input Capacitance	C _{iss}		27		рF	V _{DS} = 3.0 V, V _{GS} = 0, f = 1 MHz	
Output Capacitance	Coss		37		pF		
Feedback Capacitance	C _{rss}		8		pF		
Turn-On Delay Time	^t d(on)		100		ns		
Rise Time	t _r		300		ns	$V_{GS(on)}$ = 3.0 V, R _G = 10 Ω V_{DD} = 3.0 V, I _D = 10 mA R_{L} = 300 Ω	
Turn-Off Delay Time	td(off)	-	210		ns		
Fall Time	tf		240		ns		

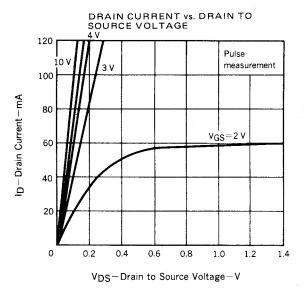
SWITCHING TIME MEASUREMENT CIRCUIT AND CONDITIONS

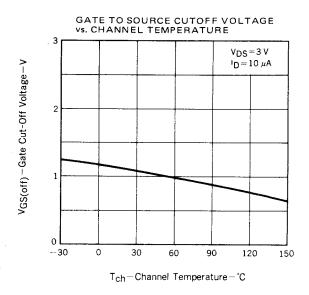


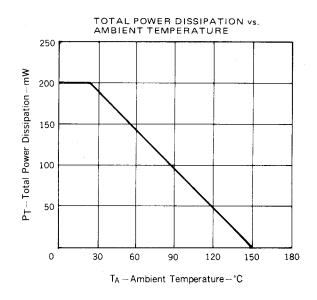


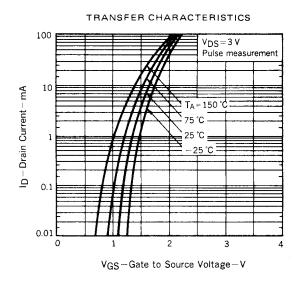
TYPICAL CHARACTERISTICS (TA = 25 °C)

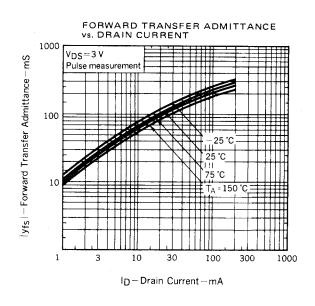


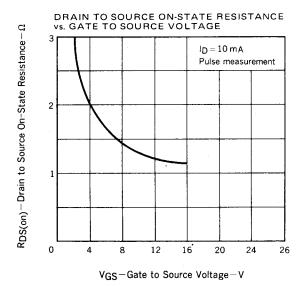


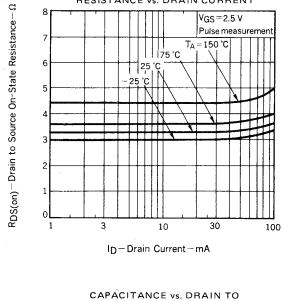




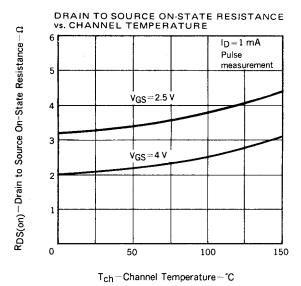


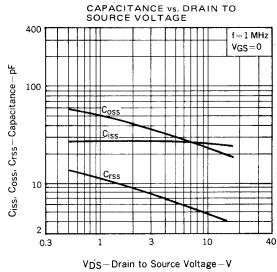


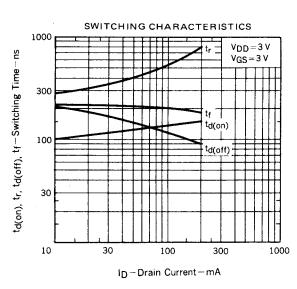


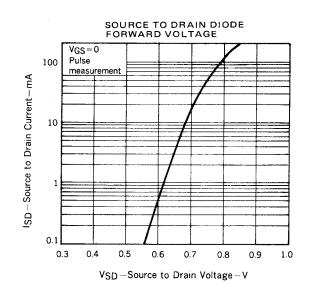


DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT









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